



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts,Customers Priority,Honest Operation,and Considerate Service",our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China

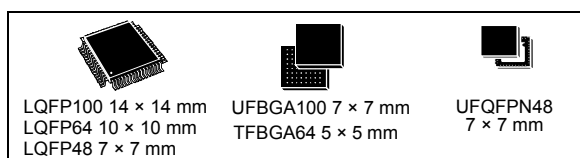


Ultra-low-power 32-bit MCU ARM[®]-based Cortex[®]-M3,
128KB Flash, 32KB SRAM, 4KB EEPROM, LCD, USB, ADC, DAC

Datasheet - production data

Features

- Ultra-low-power platform
 - 1.65 V to 3.6 V power supply
 - **-40°C to 105°C** temperature range
 - 0.28 µA Standby mode (3 wakeup pins)
 - **1.11 µA Standby mode + RTC**
 - 0.44 µA Stop mode (16 wakeup lines)
 - 1.38 µA Stop mode + RTC
 - 10.9 µA Low-power Run mode
 - 185 µA/MHz Run mode
 - 10 nA ultra-low I/O leakage
 - < 8 µs wakeup time
- Core: ARM[®] Cortex[®]-M3 32-bit CPU
 - From 32 kHz up to 32 MHz max
 - 1.25 DMIPS/MHz (Dhrystone 2.1)
 - Memory protection unit
- Reset and supply management
 - Ultra-safe, low-power BOR (brownout reset) with 5 selectable thresholds
 - Ultra-low-power POR/PDR
 - Programmable voltage detector (PVD)
- Clock sources
 - 1 to 24 MHz crystal oscillator
 - 32 kHz oscillator for RTC with calibration
 - High Speed Internal 16 MHz factory-trimmed RC (+/- 1%)
 - Internal low-power 37 kHz RC
 - Internal multispeed low-power 65 kHz to 4.2 MHz
 - PLL for CPU clock and USB (48 MHz)
- Pre-programmed bootloader
 - USART supported
- Development support
 - Serial wire debug supported
 - JTAG and trace supported
- Up to 83 fast I/Os (73 I/Os 5V tolerant), all mappable on 16 external interrupt vectors
- Memories
 - Up to 128 Kbytes Flash memory with ECC
 - Up to 32 Kbytes RAM
 - Up to 4 Kbytes of true EEPROM with ECC
 - 80 byte backup register



- LCD Driver (except STM32L151x6/8/B-A devices) for up to 8x40 segments
 - Support contrast adjustment
 - Support blinking mode
 - Step-up converter on board
- Rich analog peripherals (down to 1.8 V)
 - 12-bit ADC 1 Msps up to 24 channels
 - 12-bit DAC 2 channels with output buffers
 - 2x Ultra-low-power-comparators (window mode and wake up capability)
- DMA controller 7x channels
- 8x peripheral communication interfaces
 - 1x USB 2.0 (internal 48 MHz PLL)
 - 3x USART (ISO 7816, IrDA)
 - 2x SPI 16 Mbits/s
 - 2x I2C (SMBus/PMBus)
- 10x timers: 6x 16-bit with up to 4 IC/OC/PWM channels, 2x 16-bit basic timers, 2x watchdog timers (independent and window)
- Up to 20 capacitive sensing channels supporting touchkey, linear and rotary touch sensors
- CRC calculation unit, 96-bit unique ID

Table 1. Device summary

Reference	Part number
STM32L151CB-A, STM32L151C8-A, STM32L151C6-A, STM32L151RB-A, STM32L151R8-A, STM32L151R6-A, STM32L151VB-A, STM32L151V8-A	STM32L151CBxxA STM32L151C8xxA STM32L151C6xxA STM32L151RBxxA STM32L151R8xxA STM32L151R6xxA STM32L151VBxxA STM32L151V8xxA
STM32L152CB-A, STM32L152C8-A, STM32L152C6-A, STM32L152RB-A, STM32L152R8-A, STM32L152R6-A, STM32L152VB-A, STM32L152V8-A	STM32L152CBxxA STM32L152C8xxA STM32L152C6xxA STM32L152RBxxA STM32L152R8xxA STM32L152R6xxA STM32L152VBxxA STM32L152V8xxA

Contents

1	Introduction	9
2	Description	10
2.1	Device overview	11
2.2	Ultra-low-power device continuum	12
2.2.1	Performance	12
2.2.2	Shared peripherals	12
2.2.3	Common system strategy	12
2.2.4	Features	12
3	Functional overview	13
3.1	Low-power modes	14
3.2	ARM [®] Cortex [®] -M3 core with MPU	18
3.3	Reset and supply management	19
3.3.1	Power supply schemes	19
3.3.2	Power supply supervisor	19
3.3.3	Voltage regulator	20
3.3.4	Boot modes	20
3.4	Clock management	21
3.5	Low-power real-time clock and backup registers	23
3.6	GPIOs (general-purpose inputs/outputs)	23
3.7	Memories	24
3.8	DMA (direct memory access)	24
3.9	LCD (liquid crystal display)	25
3.10	ADC (analog-to-digital converter)	25
3.10.1	Temperature sensor	26
3.10.2	Internal voltage reference (V_{REFINT})	26
3.11	DAC (digital-to-analog converter)	26
3.12	Ultra-low-power comparators and reference voltage	27
3.13	Routing interface	27
3.14	Touch sensing	27
3.15	Timers and watchdogs	27

3.15.1	General-purpose timers (TIM2, TIM3, TIM4, TIM9, TIM10 and TIM11)	29
3.15.2	Basic timers (TIM6 and TIM7)	29
3.15.3	SysTick timer	29
3.15.4	Independent watchdog (IWDG)	29
3.15.5	Window watchdog (WWDG)	30
3.16	Communication interfaces	30
3.16.1	I ² C bus	30
3.16.2	Universal synchronous/asynchronous receiver transmitter (USART)	30
3.16.3	Serial peripheral interface (SPI)	30
3.16.4	Universal serial bus (USB)	30
3.17	CRC (cyclic redundancy check) calculation unit	31
3.18	Development support	31
4	Pin descriptions	32
5	Memory mapping	51
6	Electrical characteristics	52
6.1	Parameter conditions	52
6.1.1	Minimum and maximum values	52
6.1.2	Typical values	52
6.1.3	Typical curves	52
6.1.4	Loading capacitor	52
6.1.5	Pin input voltage	52
6.1.6	Power supply scheme	53
6.1.7	Optional LCD power supply scheme	54
6.1.8	Current consumption measurement	54
6.2	Absolute maximum ratings	55
6.3	Operating conditions	56
6.3.1	General operating conditions	56
6.3.2	Embedded reset and power control block characteristics	57
6.3.3	Embedded internal reference voltage	59
6.3.4	Supply current characteristics	60
6.3.5	Wakeup time from Low-power mode	70
6.3.6	External clock source characteristics	72
6.3.7	Internal clock source characteristics	77
6.3.8	PLL characteristics	79

6.3.9	Memory characteristics	80
6.3.10	EMC characteristics	81
6.3.11	Electrical sensitivity characteristics	82
6.3.12	I/O current injection characteristics	83
6.3.13	I/O port characteristics	84
6.3.14	NRST pin characteristics	87
6.3.15	TIM timer characteristics	88
6.3.16	Communication interfaces	89
6.3.17	12-bit ADC characteristics	95
6.3.18	DAC electrical specifications	100
6.3.19	Temperature sensor characteristics	102
6.3.20	Comparator	103
6.3.21	LCD controller (STM32L152x6/8/B-A devices only)	105
7	Package information	106
7.1	LQFP100 14 x 14 mm, 100-pin low-profile quad flat package information	106
7.2	LQFP64 10 x 10 mm, 64-pin low-profile quad flat package information	109
7.3	LQFP48 7 x 7 mm, 48-pin low-profile quad flat package information	112
7.4	UFQFPN48 7 x 7 mm, 0.5 mm pitch, package information	115
7.5	UFBGA100 7 x 7 mm, 0.5 mm pitch, ultra thin fine-pitch ball grid array package information	118
7.6	TFBGA64 5 x 5 mm, 0.5 mm pitch, thin fine-pitch ball grid array package information	121
7.7	Thermal characteristics	124
7.7.1	Reference document	125
8	Ordering information	126
9	Revision history	127

List of tables

Table 1.	Device summary	1
Table 2.	Ultra-low-power STM32L151x6/8/B-A and STM32L152x6/8/B-A device features and peripheral counts	11
Table 3.	Functionalities depending on the operating power supply range	15
Table 4.	CPU frequency range depending on dynamic voltage scaling	16
Table 5.	Working mode-dependent functionalities (from Run/active down to standby)	17
Table 6.	VLCD rail decoupling	25
Table 7.	Timer feature comparison	28
Table 8.	Legend/abbreviations used in the pinout table	38
Table 9.	STM32L151x6/8/B-A and STM32L152x6/8/B-A pin definitions	39
Table 10.	Alternate function input/output	46
Table 11.	Voltage characteristics	55
Table 12.	Current characteristics	55
Table 13.	Thermal characteristics	56
Table 14.	General operating conditions	56
Table 15.	Embedded reset and power control block characteristics	57
Table 16.	Embedded internal reference voltage calibration values	59
Table 17.	Embedded internal reference voltage	59
Table 18.	Current consumption in Run mode, code with data processing running from Flash	61
Table 19.	Current consumption in Run mode, code with data processing running from RAM	62
Table 20.	Current consumption in Sleep mode	63
Table 21.	Current consumption in Low-power run mode	64
Table 22.	Current consumption in Low-power sleep mode	65
Table 23.	Typical and maximum current consumptions in Stop mode	66
Table 24.	Typical and maximum current consumptions in Standby mode	68
Table 25.	Peripheral current consumption	69
Table 26.	Low-power mode wakeup timings	71
Table 27.	High-speed external user clock characteristics	72
Table 28.	Low-speed external user clock characteristics	73
Table 29.	HSE oscillator characteristics	73
Table 30.	LSE oscillator characteristics ($f_{LSE} = 32.768$ kHz)	75
Table 31.	HSI oscillator characteristics	77
Table 32.	LSI oscillator characteristics	77
Table 33.	MSI oscillator characteristics	78
Table 34.	PLL characteristics	79
Table 35.	RAM and hardware registers	80
Table 36.	Flash memory and data EEPROM characteristics	80
Table 37.	Flash memory, data EEPROM endurance and data retention	80
Table 38.	EMS characteristics	81
Table 39.	EMI characteristics	82
Table 40.	ESD absolute maximum ratings	82
Table 41.	Electrical sensitivities	83
Table 42.	I/O current injection susceptibility	83
Table 43.	I/O static characteristics	84
Table 44.	Output voltage characteristics	85
Table 45.	I/O AC characteristics	86
Table 46.	NRST pin characteristics	87
Table 47.	TIMx characteristics	88

Table 48.	I ² C characteristics	89
Table 49.	SCL frequency ($f_{PCLK1} = 32$ MHz, $V_{DD} = V_{DD_I2C} = 3.3$ V)	90
Table 50.	SPI characteristics	91
Table 51.	USB startup time	93
Table 52.	USB DC electrical characteristics	94
Table 53.	USB: full speed electrical characteristics	94
Table 54.	ADC clock frequency	95
Table 55.	ADC characteristics	95
Table 56.	ADC accuracy	97
Table 57.	Maximum source impedance R_{AIN} max	99
Table 58.	DAC characteristics	100
Table 59.	Temperature sensor calibration values	102
Table 60.	Temperature sensor characteristics	102
Table 61.	Comparator 1 characteristics	103
Table 62.	Comparator 2 characteristics	104
Table 63.	LCD controller characteristics	105
Table 64.	LQPF100 14 x 14 mm, 100-pin low-profile quad flat package mechanical data	107
Table 65.	LQFP64 10 x 10 mm, 64-pin low-profile quad flat package mechanical data	109
Table 66.	LQFP48 7 x 7 mm, 48-pin low-profile quad flat package mechanical data	113
Table 67.	UFQFPN48 7 x 7 mm, 0.5 mm pitch, package mechanical data	116
Table 68.	UFBGA100 7 x 7 mm, 0.5 mm pitch, ultra thin fine-pitch ball grid array package mechanical data	118
Table 69.	UFBGA100 7 x 7 mm, 0.5 mm pitch, recommended PCB design rules	119
Table 70.	TFBGA64 5 x 5 mm, 0.5 mm pitch, thin fine-pitch ball grid array package mechanical data	121
Table 71.	TFBGA64 5 x 5 mm, 0.5 mm pitch, recommended PCB design rules	122
Table 72.	Thermal characteristics	124
Table 73.	Ordering information scheme	126
Table 74.	Document revision history	127

List of figures

Figure 1.	Ultra-low-power STM32L151x6/8/B-A and STM32L152x6/8/B-A block diagram	13
Figure 2.	Clock tree	22
Figure 3.	STM32L15xVxxxA UFBGA100 ballout	32
Figure 4.	STM32L15xVxxxA LQFP100 pinout	33
Figure 5.	STM32L15xRxxxA TFBGA64 ballout	34
Figure 6.	STM32L15xRxxxA LQFP64 pinout	35
Figure 7.	STM32L15xCxxxA LQFP48 pinout	36
Figure 8.	STM32L15xCxxxA UFQFPN48 pinout	37
Figure 9.	Memory map	51
Figure 10.	Pin loading conditions	52
Figure 11.	Pin input voltage	52
Figure 12.	Power supply scheme	53
Figure 13.	Optional LCD power supply scheme	54
Figure 14.	Current consumption measurement scheme	54
Figure 15.	High-speed external clock source AC timing diagram	72
Figure 16.	Low-speed external clock source AC timing diagram	73
Figure 17.	HSE oscillator circuit diagram	75
Figure 18.	Typical application with a 32.768 kHz crystal	76
Figure 19.	I/O AC characteristics definition	87
Figure 20.	Recommended NRST pin protection	88
Figure 21.	I ² C bus AC waveforms and measurement circuit	90
Figure 22.	SPI timing diagram - slave mode and CPHA = 0	92
Figure 23.	SPI timing diagram - slave mode and CPHA = 1 ⁽¹⁾	92
Figure 24.	SPI timing diagram - master mode ⁽¹⁾	93
Figure 25.	USB timings: definition of data signal rise and fall time	94
Figure 26.	ADC accuracy characteristics	98
Figure 27.	Typical connection diagram using the ADC	98
Figure 28.	Maximum dynamic current consumption on V _{REF+} supply pin during ADC conversion	99
Figure 29.	12-bit buffered /non-buffered DAC	102
Figure 30.	LQFP100 14 x 14 mm, 100-pin low-profile quad flat package outline	106
Figure 31.	LQFP100 14 x 14 mm, 100-pin low-profile quad flat package recommended footprint	108
Figure 32.	LQFP100 14 x 14 mm, 100-pin package top view example	108
Figure 33.	LQFP64 10 x 10 mm, 64-pin low-profile quad flat package outline	109
Figure 34.	LQFP64 10 x 10 mm, 64-pin low-profile quad flat package recommended footprint	110
Figure 35.	LQFP64 10 x 10 mm, 64-pin low-profile quad flat package top view example	111
Figure 36.	LQFP48 7 x 7 mm, 48-pin low-profile quad flat package outline	112
Figure 37.	LQFP48 7 x 7 mm, 48-pin low-profile quad flat package recommended footprint	114
Figure 38.	LQFP48 7 x 7 mm, 48-pin low-profile quad flat package top view example	114
Figure 39.	UFQFPN48 7 x 7 mm, 0.5 mm pitch, package outline	115
Figure 40.	UFQFPN48 7 x 7 mm, 0.5 mm pitch, package recommended footprint	116
Figure 41.	UFQFPN48 7 x 7 mm, 0.5 mm pitch, package top view example	117
Figure 42.	UFBGA100, 7 x 7 mm, 0.5 mm pitch, ultra thin fine-pitch ball grid array package outline	118
Figure 43.	UFBGA100 7 x 7 mm, 0.5 mm pitch, ultra thin fine-pitch ball grid array package recommended footprint	119
Figure 44.	UFBGA100 7 x 7 mm, 0.5 mm pitch, package top view example	120
Figure 45.	TFBGA64 5 x 5 mm, 0.5 mm pitch, thin fine-pitch ball grid array	

	package outline	121
Figure 46.	TFBGA64, 5 x 5 mm, 0.5 mm pitch, thin fine-pitch ball grid array package recommended footprint	122
Figure 47.	TFBGA64 5 x 5 mm, 0.5 mm pitch, package top view example	123
Figure 48.	Thermal resistance suffix 6	125
Figure 49.	Thermal resistance suffix 7	125

1 Introduction

This datasheet provides the ordering information and mechanical device characteristics of the STM32L151x6/8/B-A and STM32L152x6/8/B-A ultra-low-power ARM[®] Cortex[®]-M3 based microcontrollers product line.

The ultra-low-power STM32L151x6/8/B-A and STM32L152x6/8/B-A microcontroller family includes devices in 3 different package types: from 48 to 100 pins. Depending on the device chosen, different sets of peripherals are included, the description below gives an overview of the complete range of peripherals proposed in this family.

These features make the ultra-low-power STM32L151x6/8/B-A and STM32L152x6/8/B-A microcontroller family suitable for a wide range of applications:

- Medical and handheld equipment
- Application control and user interface
- PC peripherals, gaming, GPS and sport equipment
- Alarm systems, Wired and wireless sensors, Video intercom
- Utility metering

This STM32L151x6/8/B-A and STM32L152x6/8/B-A datasheet should be read in conjunction with the STM32L1xxxx reference manual (RM0038). The document "Getting started with STM32L1xxxx hardware development" AN3216 gives a hardware implementation overview.

Both documents are available from the STMicroelectronics website www.st.com.

For information on the ARM[®] Cortex[®]-M3 core please refer to the Cortex[®]-M3 Technical Reference Manual, available from the ARM website.

Figure 1 shows the general block diagram of the device family.

Caution: This datasheet does not apply to:
– STM32L15xx6/8/B
covered by a separate datasheet.

2 Description

The ultra-low-power STM32L151x6/8/B-A and STM32L152x6/8/B-A devices incorporate the connectivity power of the universal serial bus (USB) with the high-performance ARM[®] Cortex[®]-M3 32-bit RISC core operating at a frequency of 32 MHz (33.3 DMIPS), a memory protection unit (MPU), high-speed embedded memories (Flash memory up to 128 Kbytes and RAM up to 32 Kbytes) and an extensive range of enhanced I/Os and peripherals connected to two APB buses.

All the devices offer a 12-bit ADC, 2 DACs and 2 ultra-low-power comparators, six general-purpose 16-bit timers and two basic timers, which can be used as time bases.

Moreover, the STM32L151x6/8/B-A and STM32L152x6/8/B-A devices contain standard and advanced communication interfaces: up to two I²Cs and SPIs, three USARTs and a USB. The STM32L151x6/8/B-A and STM32L152x6/8/B-A devices offer up to 20 capacitive sensing channels to simply add touch sensing functionality to any application.

They also include a real-time clock with sub-second counting and a set of backup registers that remain powered in Standby mode.

Finally, the integrated LCD controller (except STM32L151x6/8/B-A devices) has a built-in LCD voltage generator that allows to drive up to 8 multiplexed LCDs with contrast independent of the supply voltage.

The ultra-low-power STM32L151x6/8/B-A and STM32L152x6/8/B-A devices operate from a 1.8 to 3.6 V power supply (down to 1.65 V at power down) with BOR and from a 1.65 to 3.6 V power supply without BOR option. They are available in the -40 to +85 °C and -40 to +105°C temperature ranges. A comprehensive set of power-saving modes allows the design of low-power applications.



2.1 Device overview

Table 2. Ultra-low-power STM32L151x6/8/B-A and STM32L152x6/8/B-A device features and peripheral counts

Peripheral		STM32L15xCxxxA			STM32L15xRxxxA			STM32L15xVxxxA		
Flash (Kbytes)		32	64	128	32	64	128	64	128	
Data EEPROM (Kbytes)		4								
RAM (Kbytes)		16	32	32	16	32	32	32	32	
Timers	General-purpose	6								
	Basic	2								
Communication interfaces	SPI	2								
	I ² C	2								
	USART	3								
	USB	1								
GPIOs		37			51/50 ⁽¹⁾			83		
12-bit synchronized ADC Number of channels		1 14 channels			1 20/19 channels ⁽¹⁾			1 24 channels		
12-bit DAC Number of channels		2 2								
LCD (STM32L152xxxxA Only) COM x SEG		4x16			4x32/4x31 ⁽¹⁾ 8x28/8x27 ⁽¹⁾			4x44 8x40		
Comparator		2								
Capacitive sensing channels		13			20					
Max. CPU frequency		32 MHz								
Operating voltage		1.8 V to 3.6 V (down to 1.65 V at power-down) with BOR option 1.65 V to 3.6 V without BOR option								
Operating temperatures		Ambient operating temperatures: -40 to +85 °C / -40 to +105 °C Junction temperature: -40 to +110 °C								
Packages		LQFP48, UFQFPN48			LQFP64, TFBGA64			LQFP100, UFBGA100		

1. For TFBGA64 package (instead of PC3 pin there is V_{REF+} pin).

2.2 Ultra-low-power device continuum

The ultra-low-power family offers a large choice of cores and features. From a proprietary 8-bit core up to the Cortex-M3, including the Cortex-M0+, the STM8Lx and STM32Lx series offer the best range of choices to meet your requirements in terms of ultra-low-power features. The STM32 Ultra-low-power series is an ideal fit for applications like gas/water meters, keyboard/mouse, or wearable devices for fitness and healthcare. Numerous built-in features like LCD drivers, dual-bank memory, low-power Run mode, op-amp, AES-128bit, DAC, crystal-less USB and many others, allow to build highly cost-optimized applications by reducing the BOM.

Note: STMicroelectronics as a reliable and long-term manufacturer ensures as much as possible the pin-to-pin compatibility between any STM8Lx and STM32Lx devices and between any of the STM32Lx and STM32Fx series. Thanks to this unprecedented scalability, your existing applications can be upgraded to respond to the latest market features and efficiency demand.

2.2.1 Performance

All families incorporate highly energy-efficient cores with both Harvard architecture and pipelined execution: advanced STM8 core for STM8L families and ARM Cortex-M3 core for STM32L family. In addition specific care for the design architecture has been taken to optimize the mA/DMIPS and mA/MHz ratios.

This allows the ultra-Low-power performance to range from 5 up to 33.3 DMIPs.

2.2.2 Shared peripherals

STM8L15xxx and STM32L1xxxx share identical peripherals which ensure a very easy migration from one family to another:

- Analog peripherals: ADC, DAC and comparators
- Digital peripherals: RTC and some communication interfaces

2.2.3 Common system strategy

To offer flexibility and optimize performance, the STM8L15xxx and STM32L1xxxx families use a common architecture:

- Common power supply range from 1.65 V to 3.6 V, (1.65 V at power down only for STM8L15xxx devices)
- Architecture optimized to reach ultra-low consumption both in low-power modes and Run mode
- Fast startup strategy from low-power modes
- Flexible system clock
- Ultra-safe reset: same reset strategy including power-on reset, power-down reset, brownout reset and programmable voltage detector.

2.2.4 Features

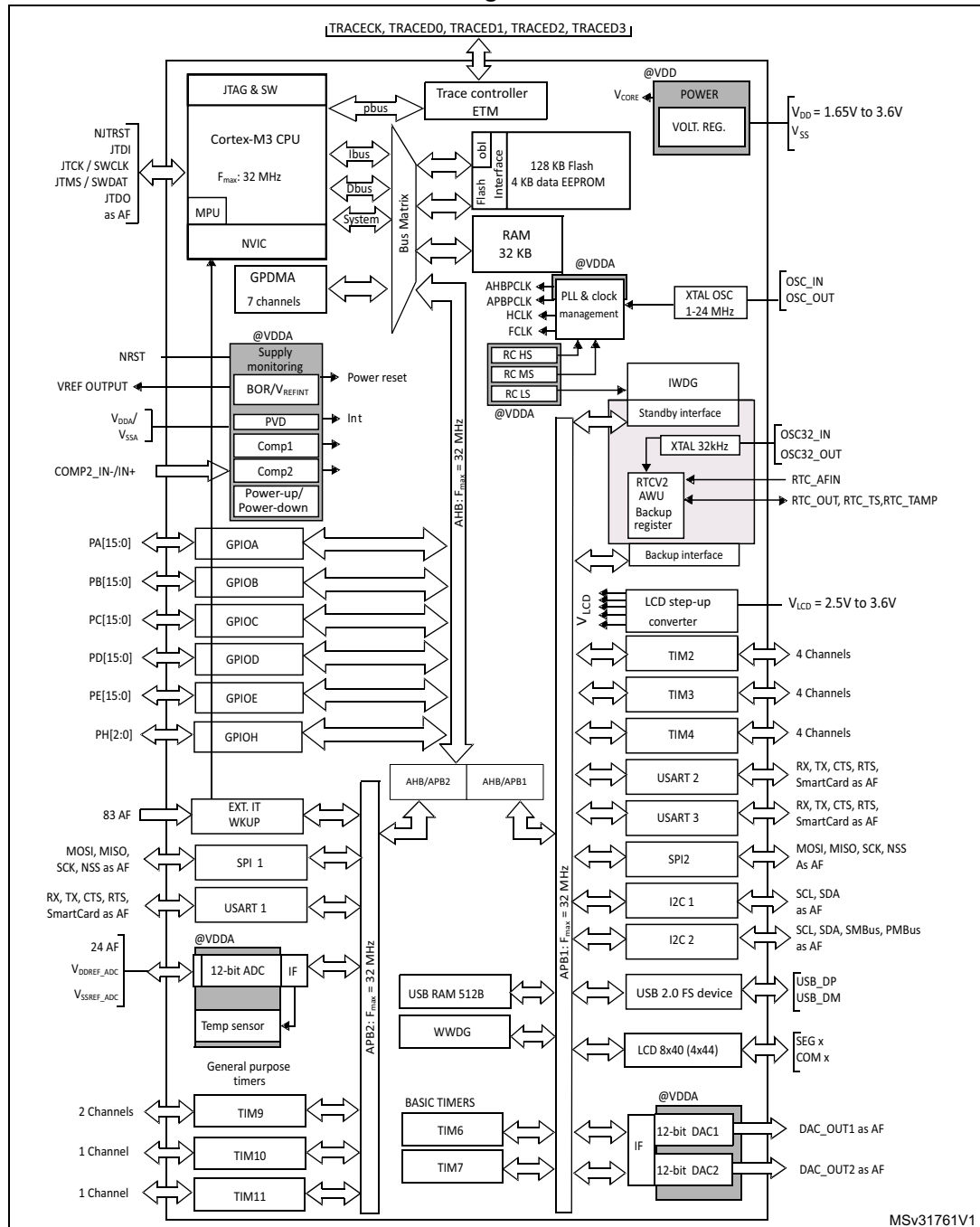
ST ultra-low-power continuum also lies in feature compatibility:

- More than 10 packages with pin count from 20 to 144 pins and size down to 3 x 3 mm
- Memory density ranging from 4 to 512 Kbytes

3 Functional overview

Figure 1 shows the block diagram.

Figure 1. Ultra-low-power STM32L151x6/8/B-A and STM32L152x6/8/B-A block diagram



1. AF = alternate function on I/O port pin.

3.1 Low-power modes

The ultra-low-power STM32L151x6/8/B-A and STM32L152x6/8/B-A devices support dynamic voltage scaling to optimize its power consumption in run mode. The voltage from the internal low-drop regulator that supplies the logic can be adjusted according to the system's maximum operating frequency and the external voltage supply:

- In Range 1 (V_{DD} range limited to 1.71-3.6 V), the CPU runs at up to 32 MHz (refer to [Table 18](#) for consumption).
- In Range 2 (full V_{DD} range), the CPU runs at up to 16 MHz (refer to [Table 18](#) for consumption)
- In Range 3 (full V_{DD} range), the CPU runs at up to 4 MHz (generated only with the multispeed internal RC oscillator clock source). Refer to [Table 18](#) for consumption.

Seven low-power modes are provided to achieve the best compromise between low-power consumption, short startup time and available wakeup sources:

- **Sleep mode**
In Sleep mode, only the CPU is stopped. All peripherals continue to operate and can wake up the CPU when an interrupt/event occurs.
Sleep mode power consumption: refer to [Table 20](#).
- **Low-power Run mode**
This mode is achieved with the multispeed internal (MSI) RC oscillator set to the minimum clock (less than 131 kHz), execution from SRAM or Flash memory, and internal regulator in low-power mode to minimize the regulator's operating current. In the low-power Run mode, the clock frequency and the number of enabled peripherals are both limited.
Low-power Run mode consumption: refer to [Table 21](#).
- **Low-power Sleep mode**
This mode is achieved by entering the Sleep mode with the internal voltage regulator in low-power mode to minimize the regulator's operating current. In the low-power Sleep mode, both the clock frequency and the number of enabled peripherals are limited; a typical example would be to have a timer running at 32 kHz.
When wakeup is triggered by an event or an interrupt, the system reverts to the run mode with the regulator on.
Low-power Sleep mode consumption: refer to [Table 22](#).
- **Stop mode with RTC**
Stop mode achieves the lowest power consumption while retaining the RAM and register contents and real time clock. All clocks in the V_{CORE} domain are stopped, the PLL, MSI RC, HSI RC and HSE crystal oscillators are disabled. The LSE or LSI is still running. The voltage regulator is in the low-power mode.
The device can be woken up from Stop mode by any of the EXTI line, in 8 μ s. The EXTI line source can be one of the 16 external lines. It can be the PVD output, the Comparator 1 event or Comparator 2 event (if internal reference voltage is on), it can be the RTC alarm(s), the USB wakeup, the RTC tamper events, the RTC timestamp event or the RTC wakeup.
- **Stop mode without RTC**
Stop mode achieves the lowest power consumption while retaining the RAM and register contents. All clocks are stopped, the PLL, MSI RC, HSI and LSI RC, LSE and HSE crystal oscillators are disabled. The voltage regulator is in the low-power mode.
The device can be woken up from Stop mode by any of the EXTI line, in 8 μ s. The EXTI

line source can be one of the 16 external lines. It can be the PVD output, the Comparator 1 event or Comparator 2 event (if internal reference voltage is on). It can also be wakened by the USB wakeup.

Stop mode consumption: refer to [Table 23](#).

- **Standby mode with RTC**

Standby mode is used to achieve the lowest power consumption and real time clock. The internal voltage regulator is switched off so that the entire V_{CORE} domain is powered off. The PLL, MSI RC, HSI RC and HSE crystal oscillators are also switched off. The LSE or LSI is still running. After entering Standby mode, the RAM and register contents are lost except for registers in the Standby circuitry (wakeup logic, IWDG, RTC, LSI, LSE Crystal 32K osc, RCC_CSR).

The device exits Standby mode in 60 μ s when an external reset (NRST pin), an IWDG reset, a rising edge on one of the three WKUP pins, RTC alarm (Alarm A or Alarm B), RTC tamper event, RTC timestamp event or RTC Wakeup event occurs.

- **Standby mode without RTC**

Standby mode is used to achieve the lowest power consumption. The internal voltage regulator is switched off so that the entire V_{CORE} domain is powered off. The PLL, MSI RC, HSI and LSI RC, HSE and LSE crystal oscillators are also switched off. After entering Standby mode, the RAM and register contents are lost except for registers in the Standby circuitry (wakeup logic, IWDG, RTC, LSI, LSE Crystal 32K osc, RCC_CSR).

The device exits Standby mode in 60 μ s when an external reset (NRST pin) or a rising edge on one of the three WKUP pin occurs.

Standby mode consumption: refer to [Table 24](#).

Note: The RTC, the IWDG, and the corresponding clock sources are not stopped by entering the Stop or Standby mode.

Table 3. Functionalities depending on the operating power supply range

Operating power supply range	Functionalities depending on the operating power supply range			
	DAC and ADC operation	USB	Dynamic voltage scaling range	I/O operation
$V_{DD} = 1.65$ to 1.71 V	Not functional	Not functional	Range 2 or Range 3	Degraded speed performance
$V_{DD} = 1.71$ to 1.8 V ⁽¹⁾	Not functional	Not functional	Range 1, Range 2 or Range 3	Degraded speed performance
$V_{DD} = 1.8$ to 2.0 V ⁽¹⁾	Conversion time up to 500 Ksps	Not functional	Range 1, Range 2 or Range 3	Degraded speed performance

Table 3. Functionalities depending on the operating power supply range (continued)

Operating power supply range	Functionalities depending on the operating power supply range			
	DAC and ADC operation	USB	Dynamic voltage scaling range	I/O operation
V _{DD} = 2.0 to 2.4 V	Conversion time up to 500 Ksps	Functional ⁽²⁾	Range 1, Range 2 or Range 3	Full speed operation
V _{DD} = 2.4 to 3.6 V	Conversion time up to 1 Msps	Functional ⁽²⁾	Range 1, Range 2 or Range 3	Full speed operation

1. CPU frequency changes from initial to final must respect " $F_{CPU\ initial} < 4 * F_{CPU\ final}$ " to limit V_{CORE} drop due to current consumption peak when frequency increases. It must also respect 5 μs delay between two changes. For example to switch from 4.2 MHz to 32 MHz, you can switch from 4.2 MHz to 16 MHz, wait 5 μs, then switch from 16 MHz to 32 MHz.
2. Should be USB-compliant from I/O voltage standpoint, the minimum V_{DD} is 3.0 V.

Table 4. CPU frequency range depending on dynamic voltage scaling

CPU frequency range	Dynamic voltage scaling range
16 MHz to 32 MHz (1ws) 32 kHz to 16 MHz (0ws)	Range 1
8 MHz to 16 MHz (1ws) 32 kHz to 8 MHz (0ws)	Range 2
2.1 MHz to 4.2 MHz (1ws) 32 kHz to 2.1 MHz (0ws)	Range 3

Table 5. Working mode-dependent functionalities (from Run/active down to standby)

Ips	Run/Active	Sleep	Low-power Run	Low-power Sleep	Stop		Standby	
					Wakeup capability	Wakeup capability		
CPU	Y	-	Y	-	-	-	-	-
Flash	Y	Y	Y	Y	-	-	-	-
RAM	Y	Y	Y	Y	Y	-	-	-
Backup Registers	Y	Y	Y	Y	Y	-	Y	-
EEPROM	Y	Y	Y	Y	Y	-	-	-
Brown-out reset (BOR)	Y	Y	Y	Y	Y	Y	Y	-
DMA	Y	Y	Y	Y	-	-	-	-
Programmable Voltage Detector (PVD)	Y	Y	Y	Y	Y	Y	Y	-
Power On Reset (POR)	Y	Y	Y	Y	Y	Y	Y	-
Power Down Rest (PDR)	Y	Y	Y	Y	Y	-	Y	-
High Speed Internal (HSI)	Y	Y	-	-	-	-	-	-
High Speed External (HSE)	Y	Y	-	-	-	-	-	-
Low Speed Internal (LSI)	Y	Y	Y	Y	Y	-	Y	-
Low Speed External (LSE)	Y	Y	Y	Y	Y	-	Y	-
Multi-Speed Internal (MSI)	Y	Y	Y	Y	-	-	-	-
Inter-Connect Controller	Y	Y	Y	Y	-	-	-	-
RTC	Y	Y	Y	Y	Y	Y	Y	-
RTC Tamper	Y	Y	Y	Y	Y	Y	Y	Y
Auto Wakeup (AWU)	Y	Y	Y	Y	Y	Y	Y	Y
LCD	Y	Y	Y	Y	Y	-	-	-
USB	Y	Y	-	-	-	Y	-	-
USART	Y	Y	Y	Y	Y	(1)	-	-
SPI	Y	Y	Y	Y	-	-	-	-
I2C	Y	Y	Y	Y	-	(1)	-	-
ADC	Y	Y	-	-	-	-	-	-

Table 5. Working mode-dependent functionalities (from Run/active down to standby) (continued)

Ips	Run/Active	Sleep	Low-power Run	Low-power Sleep	Stop		Standby	
					Wakeup capability	Wakeup capability		
DAC	Y	Y	Y	Y	Y	-	-	-
Temperature sensor	Y	Y	Y	Y	Y	-	-	-
Comparators	Y	Y	Y	Y	Y	Y	-	-
16-bit Timers	Y	Y	Y	Y	-	-	-	-
IWDG	Y	Y	Y	Y	Y	Y	Y	Y
WWDG	Y	Y	Y	Y	-	-	-	-
Touch sensing	Y	-	-	-	-	-	-	-
Systick Timer	Y	Y	Y	Y	-	-	-	-
GPIOs	Y	Y	Y	Y	Y	Y	-	3 pins
Wakeup time to Run mode	0 μ s	0.4 μ s	3 μ s	46 μ s	< 8 μ s		58 μ s	
Consumption V_{DD} =1.8V to 3.6V (Typ)	Down to 185 μ A/MHz (from Flash)	Down to 36.9 μ A/MHz (from Flash)	Down to 10.9 μ A	Down to 5.5 μ A	0.43 μ A (No RTC) V_{DD} =1.8 V		0.27 μ A (No RTC) V_{DD} =1.8 V	
					1.13 μ A (with RTC) V_{DD} =1.8 V		0.87 μ A (with RTC) V_{DD} =1.8 V	
					0.44 μ A (No RTC) V_{DD} =3.0 V		0.28 μ A (No RTC) V_{DD} =3.0 V	
					1.38 μ A (with RTC) V_{DD} =3.0 V		1.11 μ A (with RTC) V_{DD} =3.0 V	

1. The startup on communication line wakes the CPU which was made possible by an EXTI, this induces a delay before entering run mode.

3.2 ARM[®] Cortex[®]-M3 core with MPU

The ARM[®] Cortex[®]-M3 processor is the industry leading processor for embedded systems. It has been developed to provide a low-cost platform that meets the needs of MCU implementation, with a reduced pin count and low-power consumption, while delivering outstanding computational performance and an advanced system response to interrupts.

The ARM[®] Cortex[®]-M3 32-bit RISC processor features exceptional code-efficiency, delivering the high-performance expected from an ARM core in the memory size usually associated with 8- and 16-bit devices.

The memory protection unit (MPU) improves system reliability by defining the memory attributes (such as read/write access permissions) for different memory regions. It provides up to eight different regions and an optional predefined background region.

Owing to its embedded ARM core, the STM32L151x6/8/B-A and STM32L152x6/8/B-A devices are compatible with all ARM tools and software.

Nested vectored interrupt controller (NVIC)

The ultra-low-power STM32L151x6/8/B-A and STM32L152x6/8/B-A devices embed a nested vectored interrupt controller able to handle up to 45 maskable interrupt channels (not including the 16 interrupt lines of Cortex-M3) and 16 priority levels.

- Closely coupled NVIC gives low-latency interrupt processing
- Interrupt entry vector table address passed directly to the core
- Closely coupled NVIC core interface
- Allows early processing of interrupts
- Processing of *late arriving*, higher-priority interrupts
- Support for tail-chaining
- Processor state automatically saved
- Interrupt entry restored on interrupt exit with no instruction overhead

This hardware block provides flexible interrupt management features with minimal interrupt latency.

3.3 Reset and supply management

3.3.1 Power supply schemes

- $V_{DD} = 1.65$ to 3.6 V: external power supply for I/Os and the internal regulator. Provided externally through V_{DD} pins.
- V_{SSA} , $V_{DDA} = 1.65$ to 3.6 V: external analog power supplies for ADC, reset blocks, RCs and PLL (minimum voltage to be applied to V_{DDA} is 1.8 V when the ADC is used). V_{DDA} and V_{SSA} must be connected to V_{DD} and V_{SS} , respectively.

3.3.2 Power supply supervisor

The device has an integrated ZEROPOWER power-on reset (POR)/power-down reset (PDR) that can be coupled with a brownout reset (BOR) circuitry.

The device exists in two versions:

- The version with BOR activated at power-on operates between 1.8 V and 3.6 V.
- The other version without BOR operates between 1.65 V and 3.6 V.

After the V_{DD} threshold is reached (1.65 V or 1.8 V depending on the BOR which is active or not at power-on), the option byte loading process starts, either to confirm or modify default thresholds, or to disable the BOR permanently: in this case, the V_{DD} min value becomes 1.65 V (whatever the version, BOR active or not, at power-on).

When BOR is active at power-on, it ensures proper operation starting from 1.8 V whatever the power ramp-up phase before it reaches 1.8 V. When BOR is not active at power-up, the power ramp-up should guarantee that 1.65 V is reached on V_{DD} at least 1 ms after it exits the POR area.

Five BOR thresholds are available through option bytes, starting from 1.8 V to 3 V. To reduce the power consumption in Stop mode, it is possible to automatically switch off the internal reference voltage (V_{REFINT}) in Stop mode. The device remains in reset mode when V_{DD} is below a specified threshold, $V_{POR/PDR}$ or V_{BOR} , without the need for any external reset circuit.

Note: The start-up time at power-on is typically 3.3 ms when BOR is active at power-up, the start-up time at power-on can be decreased down to 1 ms typically for devices with BOR inactive at power-up.

The device features an embedded programmable voltage detector (PVD) that monitors the V_{DD}/V_{DDA} power supply and compares it to the V_{PVD} threshold. This PVD offers 7 different levels between 1.85 V and 3.05 V, chosen by software, with a step around 200 mV. An interrupt can be generated when V_{DD}/V_{DDA} drops below the V_{PVD} threshold and/or when V_{DD}/V_{DDA} is higher than the V_{PVD} threshold. The interrupt service routine can then generate a warning message and/or put the MCU into a safe state. The PVD is enabled by software.

3.3.3 Voltage regulator

The regulator has three operation modes: main (MR), low-power (LPR) and power down.

- MR is used in Run mode (nominal regulation)
- LPR is used in the Low-power run, Low-power sleep and Stop modes
- Power down is used in Standby mode. The regulator output is high impedance, the kernel circuitry is powered down, inducing zero consumption but the contents of the registers and RAM are lost except for the standby circuitry (wake-up logic, IWDG, RTC, LSI, LSE crystal 32K osc, RCC_CSR).

3.3.4 Boot modes

At startup, boot pins are used to select one of three boot options:

- Boot from Flash memory
- Boot from System Memory
- Boot from embedded RAM

The boot loader is located in System Memory. It is used to reprogram the Flash memory by using USART1 or USART2. See the application note "STM32 microcontroller system memory boot mode" (AN2606) for details.

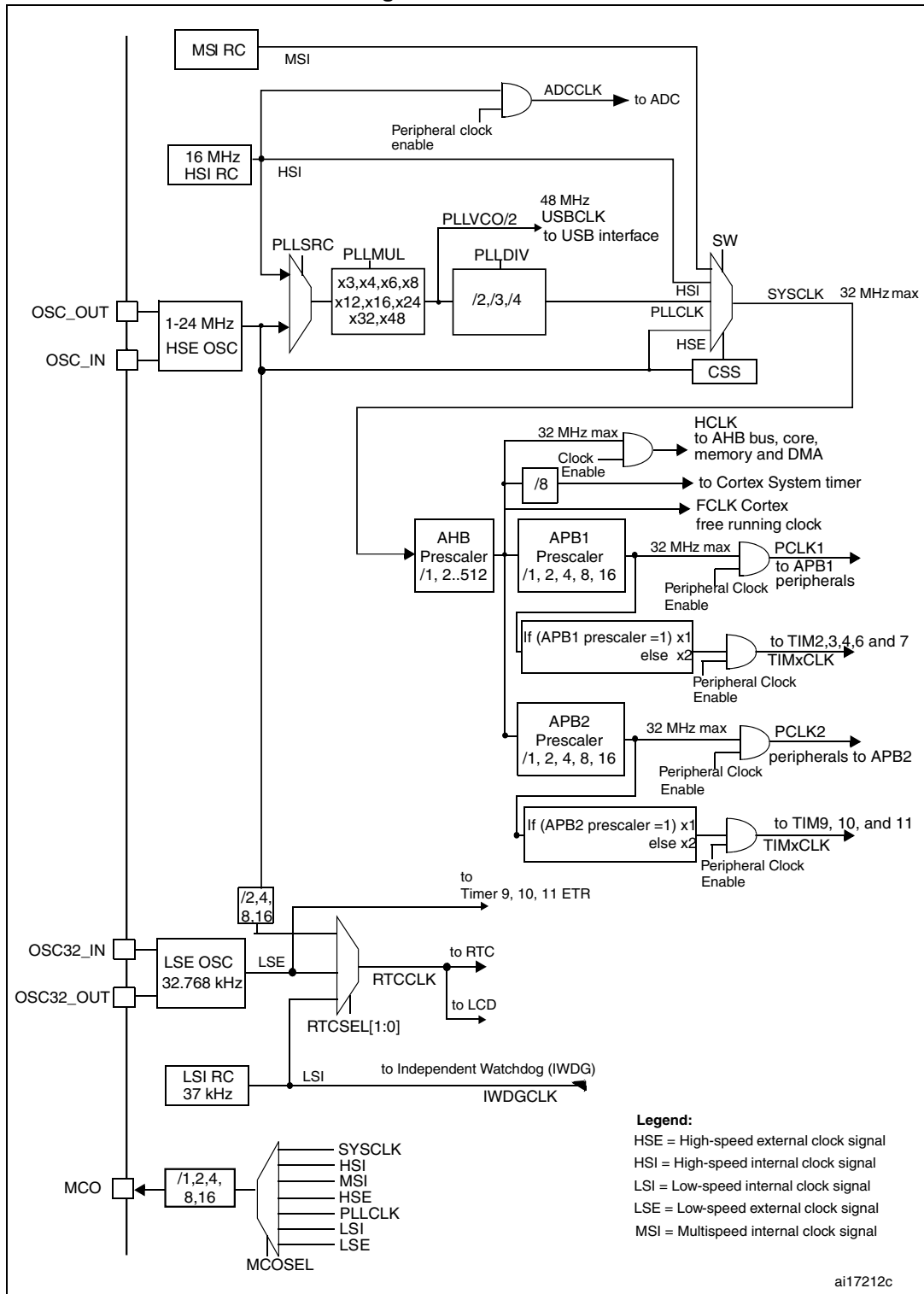
3.4 Clock management

The clock controller distributes the clocks coming from different oscillators to the core and the peripherals. It also manages clock gating for low-power modes and ensures clock robustness. It features:

- **Clock prescaler:** to get the best trade-off between speed and current consumption, the clock frequency to the CPU and peripherals can be adjusted by a programmable prescaler
- **Safe clock switching:** clock sources can be changed safely on the fly in run mode through a configuration register.
- **Clock management:** to reduce power consumption, the clock controller can stop the clock to the core, individual peripherals or memory.
- **Master clock source:** three different clock sources can be used to drive the master clock:
 - 1-24 MHz high-speed external crystal (HSE), that can supply a PLL
 - 16 MHz high-speed internal RC oscillator (HSI), trimmable by software, that can supply a PLL
 - Multispeed internal RC oscillator (MSI), trimmable by software, able to generate 7 frequencies (65.5 kHz, 131 kHz, 262 kHz, 524 kHz, 1.05 MHz, 2.1 MHz, 4.2 MHz) with a consumption proportional to speed, down to 750 nA typical. When a 32.768 kHz clock source is available in the system (LSE), the MSI frequency can be trimmed by software down to a $\pm 0.5\%$ accuracy.
- **Auxiliary clock source:** two ultra-low-power clock sources that can be used to drive the LCD controller and the real-time clock:
 - 32.768 kHz low-speed external crystal (LSE)
 - 37 kHz low-speed internal RC (LSI), also used to drive the independent watchdog. The LSI clock can be measured using the high-speed internal RC oscillator for greater precision.
- **RTC and LCD clock sources:** the LSI, LSE or HSE sources can be chosen to clock the RTC and the LCD, whatever the system clock.
- **USB clock source:** the embedded PLL has a dedicated 48 MHz clock output to supply the USB interface.
- **Startup clock:** after reset, the microcontroller restarts by default with an internal 2.1 MHz clock (MSI). The prescaler ratio and clock source can be changed by the application program as soon as the code execution starts.
- **Clock security system (CSS):** this feature can be enabled by software. If a HSE clock failure occurs, the master clock is automatically switched to HSI and a software interrupt is generated if enabled.
- **Clock-out capability (MCO: microcontroller clock output):** it outputs one of the internal clocks for external use by the application.

Several prescalers allow the configuration of the AHB frequency, the high-speed APB (APB2) and the low-speed APB (APB1) domains. The maximum frequency of the AHB and the APB domains is 32 MHz. See [Figure 2](#) for details on the clock tree.

Figure 2. Clock tree



3.5 Low-power real-time clock and backup registers

The real-time clock (RTC) is an independent BCD timer/counter. Dedicated registers contain the sub-second, second, minute, hour (12/24 hour), week day, date, month, year, in BCD (binary-coded decimal) format. Correction for 28, 29 (leap year), 30, and 31 day of the month are made automatically. The RTC provides two programmable alarms and programmable periodic interrupts with wakeup from Stop and Standby modes.

The programmable wakeup time ranges from 120 μ s to 36 hours.

The RTC can be calibrated with an external 512 Hz output, and a digital compensation circuit helps reduce drift due to crystal deviation. The RTC can also be automatically corrected with a 50/60Hz stable power line.

The RTC calendar can be updated on the fly down to sub second precision, which enables network system synchronization. A time stamp can record an external event occurrence, and generates an interrupt.

There are twenty 32-bit backup registers provided to store 80 bytes of user application data. They are cleared in case of tamper detection. Three pins can be used to detect tamper events. A change on one of these pins can reset backup register and generate an interrupt. To prevent false tamper event, like ESD event, these three tamper inputs can be digitally filtered.

3.6 GPIOs (general-purpose inputs/outputs)

Each of the GPIO pins can be configured by software as output (push-pull or open-drain), as input (with or without pull-up or pull-down) or as peripheral alternate function. Most of the GPIO pins are shared with digital or analog alternate functions, and can be individually remapped using dedicated AFIO registers. All GPIOs are high current capable. The alternate function configuration of I/Os can be locked if needed following a specific sequence in order to avoid spurious writing to the I/O registers. The I/O controller is connected to the AHB with a toggling speed of up to 16 MHz.

External interrupt/event controller (EXTI)

The external interrupt/event controller consists of 23 edge detector lines used to generate interrupt/event requests. Each line can be individually configured to select the trigger event (rising edge, falling edge, both) and can be masked independently. A pending register maintains the status of the interrupt requests. The EXTI can detect an external line with a pulse width shorter than the Internal APB2 clock period. Up to 83 GPIOs can be connected to the 16 external interrupt lines. The 7 other lines are connected to RTC, PVD, USB or Comparator events.

3.7 Memories

The STM32L151x6/8/B-A and STM32L152x6/8/B-A devices have the following features:

- Up to 32 Kbytes of embedded RAM accessed (read/write) at CPU clock speed with 0 wait states. With the enhanced bus matrix, operating the RAM does not lead to any performance penalty during accesses to the system bus (AHB and APB buses).
- The non-volatile memory is divided into three arrays:
 - 32, 64 or 128 Kbyte of embedded Flash program memory
 - 4 Kbytes of data EEPROM
 - Options bytes

The options bytes are used to write-protect or read-out-protect the memory (with 4 KB granularity) and/or readout-protect the whole memory with the following options:

- Level 0: no readout protection
- Level 1: memory readout protection, the Flash memory cannot be read from or written to if either debug features are connected or boot in RAM is selected
- Level 2: chip readout protection, debug features (Cortex-M3 JTAG and serial wire) and boot in RAM selection disabled (JTAG fuse)

The whole non-volatile memory embeds the error correction code (ECC) feature.

The user area of the Flash memory can be protected against Dbus read access by the PCROP feature (see RM0038 for details).

3.8 DMA (direct memory access)

The flexible 7-channel, general-purpose DMA is able to manage memory-to-memory, peripheral-to-memory and memory-to-peripheral transfers. The DMA controller supports circular buffer management, avoiding the generation of interrupts when the controller reaches the end of the buffer.

Each channel is connected to dedicated hardware DMA requests, with software trigger support for each channel. Configuration is done by software and transfer sizes between source and destination are independent.

The DMA can be used with the main peripherals: SPI, I²C, USART, general-purpose timers and ADC.

3.9 LCD (liquid crystal display)

The LCD drives up to 8 common terminals and 44 segment terminals to drive up to 320 pixels.

- Internal step-up converter to guarantee functionality and contrast control irrespective of V_{DD} . This converter can be deactivated, in which case the V_{LCD} pin is used to provide the voltage to the LCD
- Supports static, 1/2, 1/3, 1/4 and 1/8 duty
- Supports static, 1/2, 1/3 and 1/4 bias
- Phase inversion to reduce power consumption and EMI
- Up to 8 pixels can be programmed to blink
- Unneeded segments and common pins can be used as general I/O pins
- LCD RAM can be updated at any time owing to a double-buffer
- The LCD controller can operate in Stop mode
- V_{LCD} rail decoupling capability

Table 6. V_{LCD} rail decoupling

	Bias			Pin	
	1/2	1/3	1/4		
$V_{LCDrail1}$	1/2 V_{LCD}	2/3 V_{LCD}	1/2 V_{LCD}	PB2	
$V_{LCDrail2}$	NA	1/3 V_{LCD}	1/4 V_{LCD}	PB12	PE11
$V_{LCDrail3}$	NA	NA	3/4 V_{LCD}	PB0	PE12

3.10 ADC (analog-to-digital converter)

A 12-bit analog-to-digital converters is embedded into STM32L151x6/8/B-A and STM32L152x6/8/B-A devices with up to 24 external channels, performing conversions in single-shot or scan mode. In scan mode, automatic conversion is performed on a selected group of analog inputs.

The ADC can be served by the DMA controller.

An analog watchdog feature allows very precise monitoring of the converted voltage of one, some or all selected channels. An interrupt is generated when the converted voltage is outside the programmed thresholds.

The events generated by the general-purpose timers (TIMx) can be internally connected to the ADC start trigger and injection trigger, to allow the application to synchronize A/D conversions and timers. An injection mode allows high priority conversions to be done by interrupting a scan mode which runs in as a background task.

The ADC includes a specific low-power mode. The converter is able to operate at maximum speed even if the CPU is operating at a very low frequency and has an auto-shutdown function. The ADC's runtime and analog front-end current consumption are thus minimized whatever the MCU operating mode.